Specifications

Drawing No.	USY1P-H1-16610-00	1/10
Issued Date.	Jun,14 ,2016	

Messrs: Digi-Key

Note: In case of specification change, KYOCERA Part Number also will be changed.

Product Name	Crystal Units with Thermistor			
Product Model	CT1612DB			
Frequency	38400kHz			
Customer Part Number	-			
Customer Specification Number	-			
KYOCERA Part Number	CT1612DB38400C0FLHA1			
Remarks Pb-Free, RoHS Compliant, MSL 1				

Customer Acceptance

Accept Signature	Approved Date	
	Department	
	Person in charge	

Seller

KYOCERA Crystal Device Corporation

(Sales Division)

6 Takeda Tobadono-cho, Fushimi-ku, Kyoto

612-8501 Japan

TEL. No. 075-604-3421 FAX. No. 075-604-3469 Manufacturer

KYOCERA Crystal Device Corporation

(Marketing & Sales Engineering Division)

5850, Higashine-Koh, Higashine-Shi, Yamagata

999-3701 Japan

TEL. No. 0237-43-5611 FAX. No. 0237-43-5615

Design Department	Quality Assurance	Approved by	Checked by	Issued by
KYOCERA Crystal Device Corporation	S.Itoh	T.Soda	A.Muraoka	Y.Nozaki
Crystal Unit Application Engineering Section				
Crystal Units Division				

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Revision History

Rev.No.	Description of revise	Date	Approved by	Checked by	Issued by
00	First Edition	Jun,14,2016	T.Soda	A.Muraoka	Y.Nozaki

1. APPLICATION

This specification sheet is applied to Crystal Units with Thermistor "CT1612DB"

2. KYOCERA PART NUMBER

CT1612DB38400C0FLHA1

3. RATINGS

Items	SYMB.	Rating	Unit	Remarks
Operating Temperature range	Topr	-30~+105	°C	
Storage Temperature range	Tstg	-40~+105	°C	

4. CHARACTERISTICS

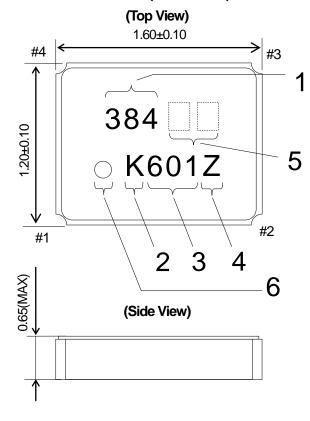
4-1 ELECTRICAL CHARACTERISTICS

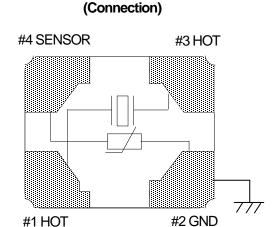
Items		Electrical Specification			Test Condition	Remarks	
	SYMB.	Min	Тур.	Max	Unit		
Mode of Vibration		Fu	ındamen	tal			
Nominal Frequency	F0		38.4		MHz		
Nominal Temperature	T _{NOM}		29		°C		
Load Capacitance	CL		7.0		pF		
Frequency Tolerance	dF	-10.0		+10.0		+25±3°C	
Frequency	dF_T	-12.0		+12.0	nnm	-30~+85°C	
Temperature					ppm		
Characteristics							
Equivalent Series	ESR			80	Ω		
Resistance							
Drive Level	Pd	0.01	0.05	0.1	mW		
Insulation Resistance	IR	500			MΩ	100V(DC)	

4-2 ELECTRICAL CHARACTERISTICS (Thermistor)

Items	Electrical Specification					Remarks
	SYMB.	Min	Тур.	Max	Unit	
Resistance			100		kΩ	25°C
B-Constant			4250		K	25°C - 50°C
Tolerance		-1.0		1.0	%	

5. APPEARANCES, DIMENSIONS OUTLINE DIMENSION (not to scale)

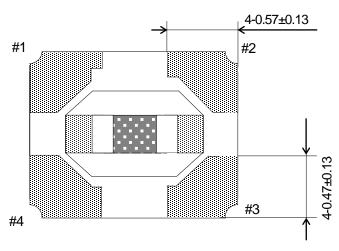




(Top View)

PIN No.	PIN Layout	
#1	НОТ	
#2	GND	
#3	НОТ	
#4	SENSOR	

(Bottom View)



UNIT: mm

MARKING

1 Nominal Frequency

2 Identification

3 Date Code

First 3digits of the frequency are indicated.

[K] is to indicate 1Pin direction

Last 1 Digit of YEAR and WEEK

(Ex) 2016,Jan, 5 → 601

4 Manufacturing Location

Y → Japan(Yamagata)

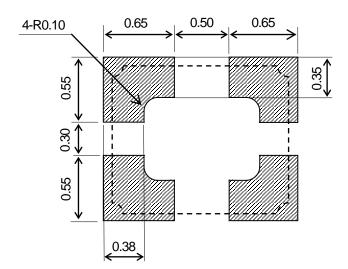
Z → Japan (Shiga Yohkaichi)

5 Option Code

Alphabet & Number 2digits or blank.(For T-Sensor)

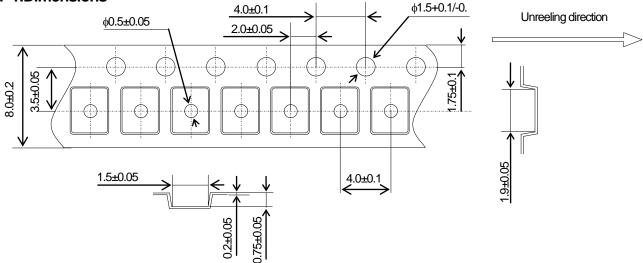
6 1Pin mark

6. RECOMMENDED LAND PATTERN (not to scale)

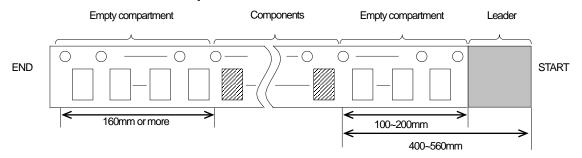


UNIT:mm

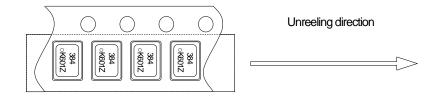
7-1. Dimensions



7-2.Leader and trailer tape

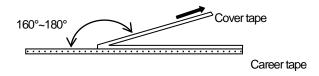


7-3. Direction (The direction shall be seen from the top cover tape side)

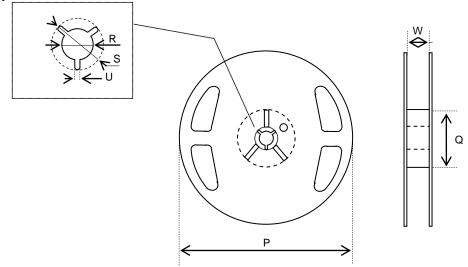


7-4. Specification

- 1. Material of the carrier tape is either polystyrene or A-PET (ESD).
- 2. Material of the cover tape is polyester (ESD).
- 3. The seal tape shall not cover the sprocket holes and not protrude from the carrier tape.
- 4. Tensile strength of carrier tape: 10N or more.
- 5. The R of the corner of each cavity is 0.2RMAX.
- 6. The alignment between centers of the cavity and sprocket hole shall be 0.05mm or less.
- 7. The orientation shall be checked from the top cover tape side as shown in 7-3.
- 8. Peeling force of cover tape: 0.1 to 1.0N.
- 9. The component will fall out naturally when cover tape is removed and set upside down.
- 10. Surface resistivity \rightarrow Carrier tape: $\ge 1 \times 10^7$, Cover tape :> 1×10^{11}



Reel specifications



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Symbol	Р	Q	R
Dimension	φ180 +0/-3	φ60 +1/-0	φ13±0.2
Symbol	S	U	W
Dimension	φ21±0.8	2.0±0.5	9±1

(Unit: mm)

φ330 Reel(15000pcs)

Symbol	Р	Q	R
Dimension	ф330±2.0	ф100±1.0	φ13±0.2
Symbol	S	U	W
Dimension	ф21±0.8	2.0±0.5	9.4±0.5

(Unit: mm)

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8. Cautions for use

(1) Soldering upon mounting

There is a possibility to influence product characteristics when Solder paste or conductive glue comes in contact with product lid or surface.

(2) When using mounting machine

Please minimize the shock when using mounting machine to avoid any excess stress to the product.

(3) Conformity of a circuit

We strongly recommend to make sure that Negative resistance (Gain) of IC is designed to be 3 times the ESR (Equivalent Series Resistance) of crystal unit.

9. Storage conditions

Please store product in below conditions, and use within 6 months.

Temperature +18 to +30°C, and Humidity of 20 to 70 % in the packaging condition.

10. Manufacturing location

Kyocera Crystal Device Corporation Yamagata Plant

Kyocera Crystal Device Corporation Shiga Yohkaichi Plant

Kyocera Crystal Device (Thailand) Co., Ltd

11. Quality Assurance

To be guaranteed by Kyocera Crystal Device Quality Assurance Division

12. Quality guarantee

In case when Kyocera Crystal Device Corporation rooted failure occurred within 1 year after its delivery, substitute product will be arranged based on discussion. Quality guarantee of product after 1 year of its delivery is waivered.

13. Others

In case of any questions or opinions regarding the Specification, please have it in written manner within 45 days after issued date.